

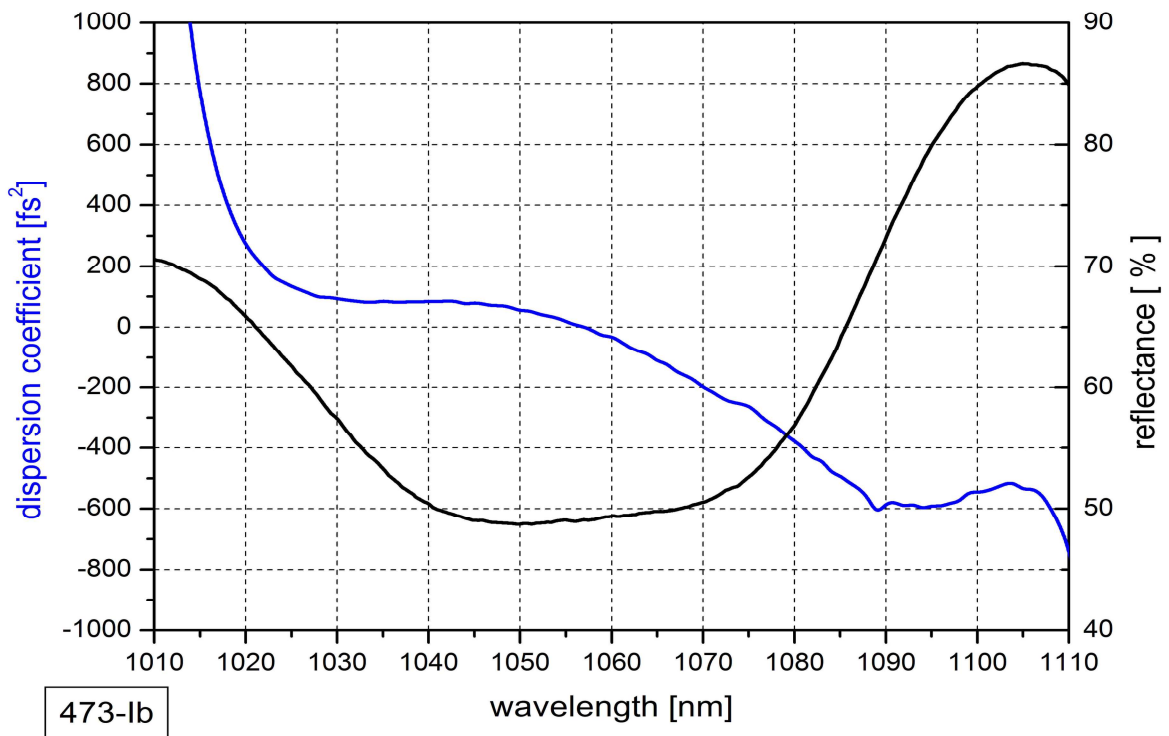
SAM™ Data Sheet SAM-1040-50-12ps-x, $\lambda = 1040$ nm

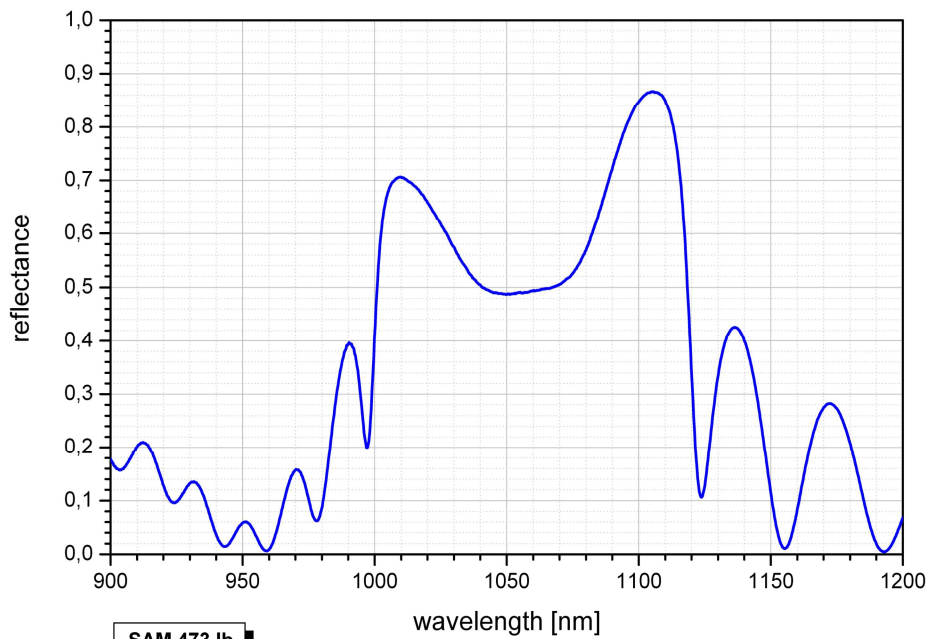
Laser wavelength	$\lambda = 1040$ nm
High reflection band	$\lambda = 1010 \dots 1110$ nm
Absorbance	$A_0 = 50$ %
Modulation depth	$\Delta R = 40$ %
Non-saturable loss	$A_{ns} = 10$ %
Saturation fluence	$\Phi_{sat} = 19 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 12$ ps
Damage threshold	$\Phi = 800 \mu\text{J}/\text{cm}^2$
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance and dispersion coefficient D_2



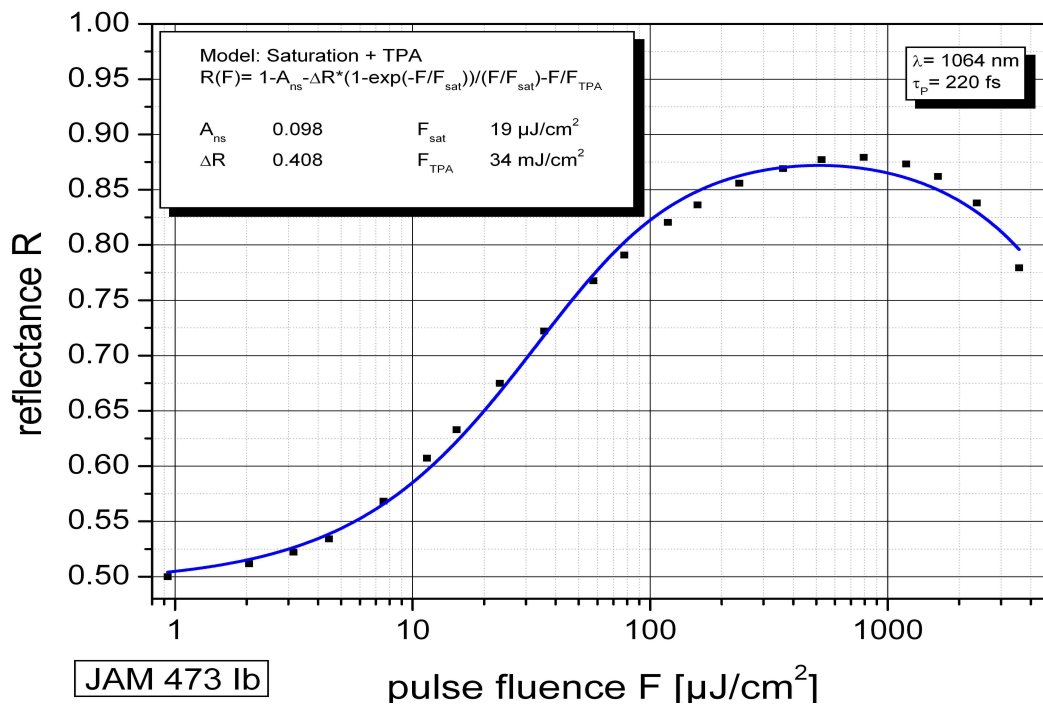


Group Delay Dispersion (GDD)

Dispersion coefficient $D_2(\omega) = \frac{\partial^2 \varphi}{\partial \omega^2}$ with φ - reflected phase

$$\omega = 2\pi \frac{c}{\lambda} \text{ - angular frequency}$$

Saturation measurement



Pump-probe measurement

